

BC807-16W / -25W / -40W



PNP SURFACE MOUNT TRANSISTOR

Features

Ideally Suited for Automatic Insertion

Epitaxial Planar Die Construction

For Switching, AF Driver and Amplifier Applications

Complementary NPN Types Available (BC817-xxW)

Lead Free By Design/RoHS Compliant (Note 1)

"Green" Device (Note 2)

Mechanical Data

Case: SOT-323

Case Material: Molded Plastic. "Green" Molding Compound.

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020C

Terminals: Finish - Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208

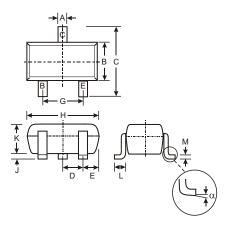
Pin Connections: See Diagram

Approximate Weight: 0.006 grams

Marking:

P/N	Marking
BC807-16W	K5A
BC807-25W	K5B
BC807-40W	K5C

Ordering & Date Code Information: See Page 3



	SOT-323									
Dim	Min	Max								
Α	0.25	0.40								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 N	ominal								
E	0.30 0.40									
G	1.20	1.40								
Н	1.80	2.20								
J	0.0	0.10								
K	0.90	1.00								
L	0.25	0.40								
М	0.10	0.18								
0 8										
All Dimensions in mm										

Maximum Ratings @T_A = 25°C unless otherwise specified

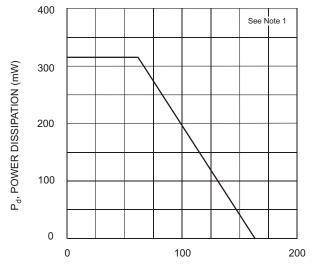
Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current	Ic	-500	mA
Peak Collector Current	I _{CM}	-1000	mA
Peak Emitter Current	I _{EM}	-1000	mA
Power Dissipation at T _{SB} = 50°C (Note 3)	Pd	200	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	R _{JA}	625	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

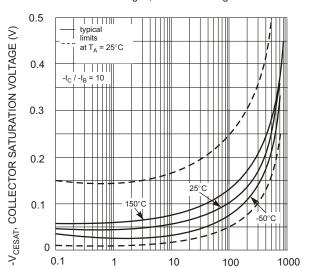
Characte	Symbol	Min	Тур	Max	Unit	Test Condition	
DC Current Gain	Current Gain Group -16 -25 -40 Current Gain Group -16 -25 -40	h _{FE}	100 160 250 60 100 170	-	250 400 600 — —	_	$V_{CE} = -1.0V, I_{C} = -100mA$ $V_{CE} = -1.0V, I_{C} = -300mA$
Collector-Emitter Saturation	V _{CE(SAT)}	_	_	-0.7	V	I _C = -500mA, I _B = -50mA	
Base-Emitter Voltage			_	_	-1.2	V	V _{CE} = -1.0V, I _C = -300mA
Collector-Emitter Cutoff Cu	rrent	I _{CES}	_	_	-100 -5.0	nΑ μΑ	$V_{CE} = -45V$ $V_{CE} = -25V$, $T_j = 150^{\circ}C$
Emitter-Base Cutoff Curren	nt	I _{EBO}	_	_	-100	nA	V _{EB} = -4.0V
Gain Bandwidth Product		f⊤	100	_	_	MHz	$V_{CE} = -5.0V, I_{C} = -10mA, f = 50MHz$
Collector-Base Capacitance			_	_	12	pF	V _{CB} = -10V, f = 1.0MHz

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Short duration pulse test used to minimize self-heating effect.

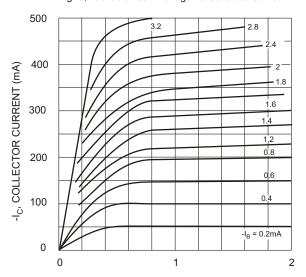




 T_{SB} , SUBSTRATE TEMPERATURE (°C) Fig. 1, Power Derating Curve



-I_C, COLLECTOR CURRENT (mA)
Fig. 3, Collector Sat. Voltage vs Collector Current



-V_{CE}, COLLECTOR-EMITTER VOLTAGE (V) Fig. 5, Typical Emitter-Collector Characteristics

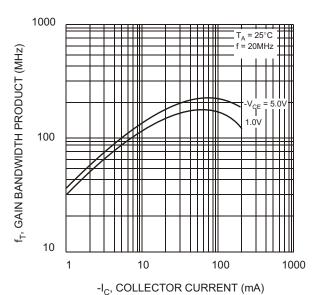
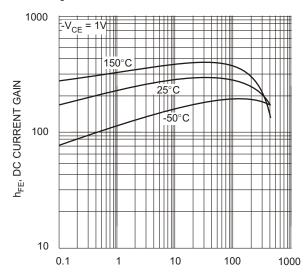
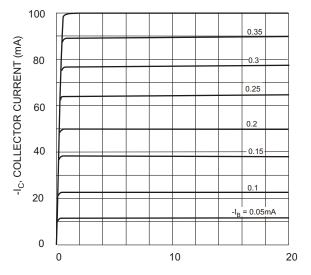


Fig. 2, Gain-Bandwidth Product vs Collector Current



-I_C, COLLECTOR CURRENT (mA)
Fig. 4, DC Current Gain vs Collector Current



-V_{CE}, COLLECTOR-EMITTER VOLTAGE (V) Fig. 6, Typical Emitter-Collector Characteristics



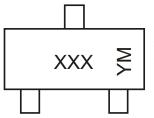
Ordering Information (Note 5)

Device*	Packaging	Shipping
BC807-xxW-7	SOT-323	3000/Tape & Reel

Notes:

- 5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.
 - * xx = gain group, e.g. BC807-16W-7.

Marking Information



XXX = Product Type Marking Code (See Page 1), e.g. K5A = BC807-16

YM = Date Code Marking

Y = Year ex: S = 2005

M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	Т	U	V	W	X	Υ	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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